Power Efficient Class AB Op-Amps with High and Symmetrical Slew Rate

Eswara Prasanna Kumar P
M.Tech DECS,
Department of ECE,
Srinivasa Institute of Technology &
Sciences, Kadapa,
AndhraPradesh, INDIA.

Madhukar Babu A
Assistant Professor,
Department of ECE,
Srinivasa Institute of Technology &
Sciences, Kadapa,
AndhraPradesh, INDIA.

Nagendra Prasad G
Associate Professor,
Department of ECE,
Srinivasa Institute of Technology &
Sciences, Kadapa,
AndhraPradesh, INDIA.

ABSTRACT:

We introduced various class AB two stage op-amps with high and approximately symmetrical slew rate and very simple architecture are introduced. A combination of adoptive loads and current replicating branch with scaled-down transistors is used to implement a push-pull output stage with maximum output current several times higher than the bias current.post layout simulation and measurement results are presented and verify a 400%-500% slew rate and 80%-100%GB enhancement with only 5% additional quiescent power dissipation and 20% silicon area increase.

Keywords:

Symmetrical slew rate, operational amplifiers, class AB operation, gain, CMOS analog integrated circuits.

I. INTRODUCTION:

In single-stage op-amps achieves highly symmetrical slew rate by using different efficient schemes. A drawback of a single stage op-amp is that relatively low open-loop gain(AOL).since the output cascading transistors is to increase the output resistances(Rout) would seriously limit the maximum output current and the slew rate enhancement factor .In the conventional class-A two-stage Miller-compensated op-amp is characterized by a highly asymmetrical slew rate with large positive slew rate and much lower negative slew rate . This lower negative-slew rate is due to the output transistor (MoN) acts as a dc current source with value 2IB and increase the static power dissipation . To avoid this limitation many class AB two-stage op-amps have been reported.

Most of them feature is relatively modest effective slew rate improvement and require additional complex circuitry, and non negligible additional static power dissipation or increased supply requirements. This decreases their current efficiency .In fig (b) achieves class AB operation with additional small hardware. It consists of a large resistive R large and small capacitor C bat This combination operates as a open battery that transfers ac variations taking place at the gate of Mop to the gate of Mon transistors .The output stage operates as a push-pull amplifier and provides dynamic class-AB operation with large positive and negative output currents. This does not increase power dissipation or supply requirements but operates only for dynamic changes with frequencies.

II. CLASS AB TWO-STAGE OP-AMPS PROPOSED:
A.Op-Amp with Current Replication Branch:

To achieve class AB operation, the output transistor MoN can be transformed into an active amplifing device by simply adding a current replicating branch formed by M2R and MoNR as shown in fig1(c).This transfers current variations Ia in M1-M2 to the output transistor MoN and increases and increases the maximum positive output current by 2IB. The maximum negative current is still limited to a value of 2IB.The current replicating branch does not require additional compensation circuit. Since the node Vx with gain in the current replicating branch is gate to the drain of MoN, and at the higher frequencies miller compensation causes MoP to behave as low impedance load. This reduces the gain between the gate of MoN and the op-amps output terminal to closely a unity value.

The current replicating branch has small dimensions reducing area and static power dissipation.In order to achieve large negative output currents, a non-linear adoptive load can be used. This modification is seen in another circuit.

B. Class AB Two-Stage Op-Amp Using Adaptive Loads:

By using an adaptive load at the input side in the circuit we can achieve class AB operation efficiently. Two different alternatives are shown in fig (d) and fig (e).In both cases, the adoptive loads manoeuvre the large variation of output resistance of transistors between triode and saturation regions in quiescent conditions. In both schemes a current increase in IA causes transistors to go in triode region and to develop large drain-source voltages. These changes cause large currents flow in the output transistors Mop and thanks to the current replicating branch, MoN.

A bias voltage with value Vb triode=Vss+Vgs+VDSsat= VTH+2VDSsat is required at the gate of MoNR. Where VDSsat= Vgs-Vth is the minimum Vds voltage to operate in saturation region. This Vbtroide leaves a quiescent drain-source voltage for MoNtriode with value VDSsat, which causes MoNtriode to operate at the boundary between the triode and saturation regions.The circuit of fig (2) is denoted as operational amplifier with current replicating branch and adaptive loads. These topologies are not harmful in terms of stability of the ac responses. The current replicating branch helps compensating the current through the miller capacitor just as in other multipath miller zero-cancellation scheme.
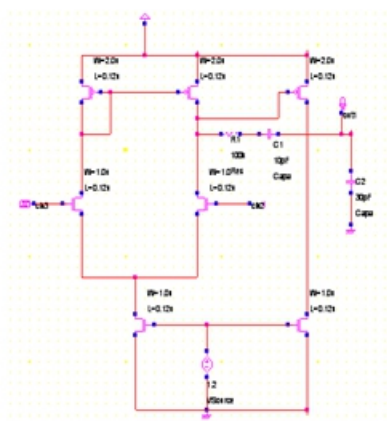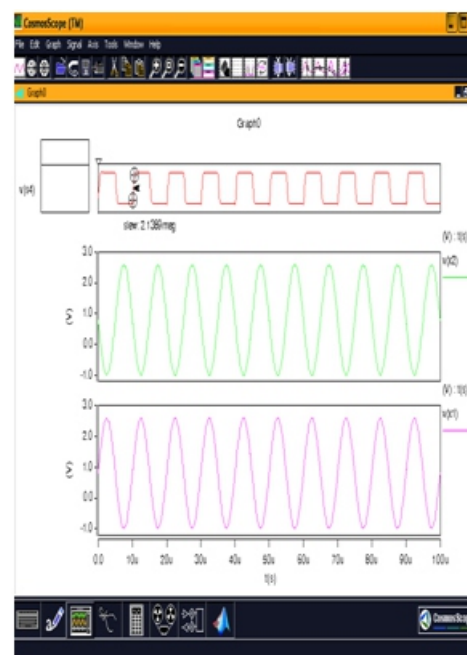
III.SIMULATION RESULTS:
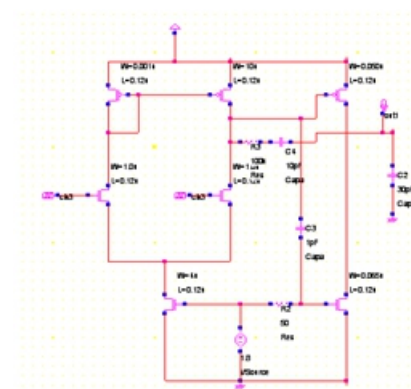

Fig 1(b). Output result Conventional class A two-stage miller op-amp

Fig 2(a).Schematic of free class AB op-amp

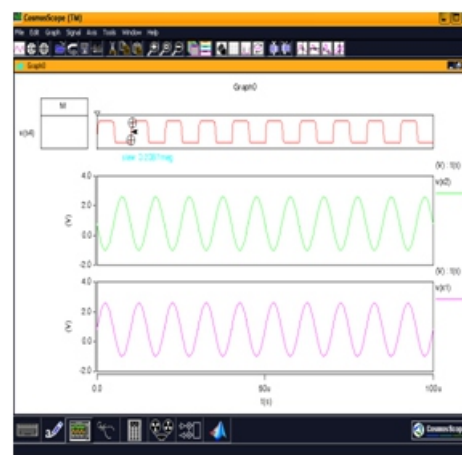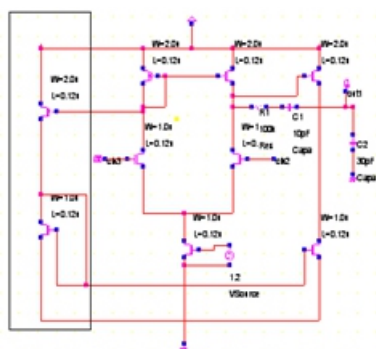Fig 2(b).Output waveform free class AB op-amp

Fig 1(a) .Schematic of Conventional class A two-stage miller op-amp

Fig 3(a) Schematic of push pulls op-amp with current replication branch.
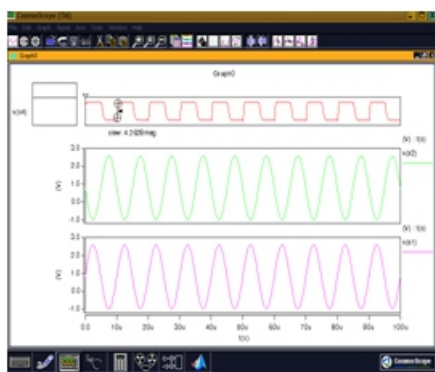

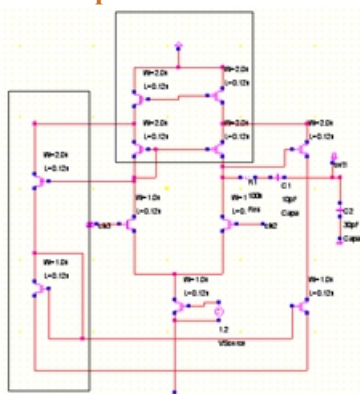**Fig 3(b).Output waveform of push pulls op-amp with current replication branch**

Fig 4(a).Schematic of class AB two stage op-amps with current replicating branch using adoptive loadII

Fig 4(b).Output waveform of class AB two stage p-amps with current replicating branch using adoptive load II.
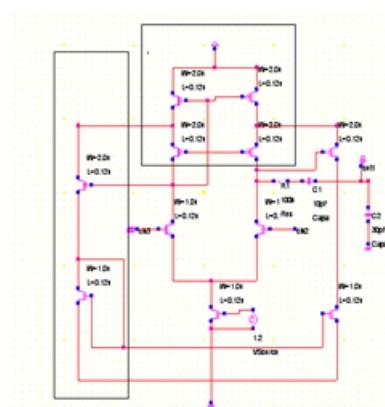

Fig 5(a).Schematic of Class AB two stage op-amp with current replicating branch using adaptive load I at the input stage.
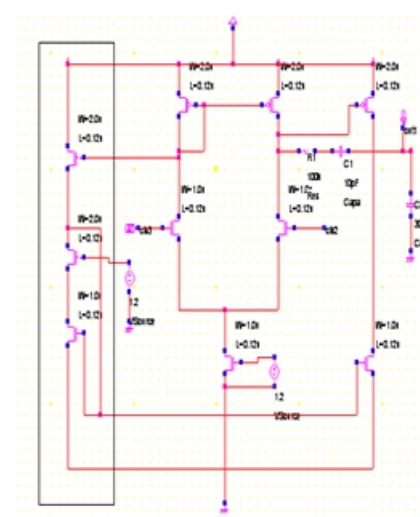

Fig 5(b).Schematic of class AB two-stage op-amp with current replicating branch using an adaptive load.
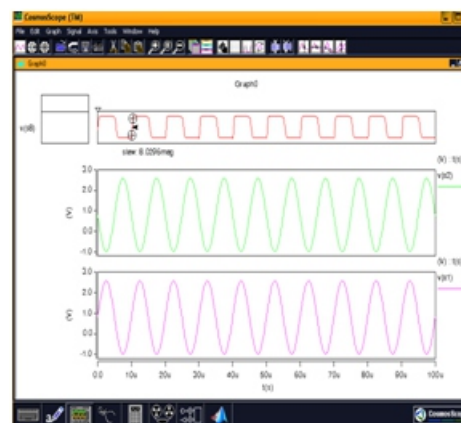

Fig 6(a).Output waveform of Class AB two stage op-amp with current replicating branch using adaptive load I at the input stage.
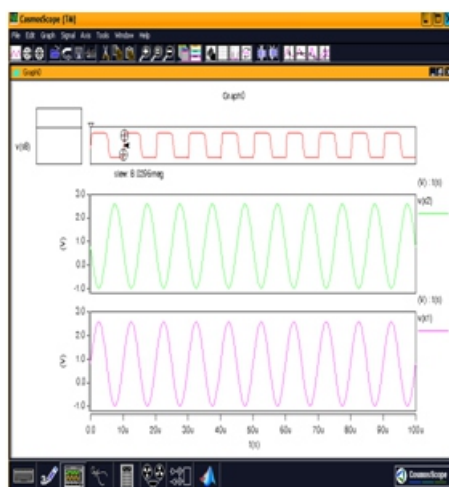
Fig 6(b).Output waveform of class AB two-stage op-amp with current replicating branch using an adaptive load

IV.COMPARISION TABLE:

CIRCUIT NAME	SLEW RATE (V/µS)	POWER (MW)
(a) Conventional two stage op-amp	2.1389Meg	2.761
(b)Free class ab op amp	3.2387 Meg	1.8597
(c) Push pull op-amp with current replication branch	4.2628 Meg	2.2329
(d) Class ab two stage op amp with current replication branch and adoptive loads	7.8397 Meg	2.2818
(e) Class AB two stage op-amp with current replication branch using adoptive load I at the input stage	8.0296 Meg	6.3124
(f) Proposed	8.435 Meg	1.1636

COMPARISION GRAPH:
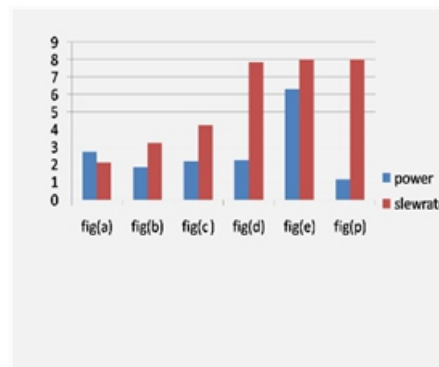
V.ACKNOWLEDGMENT:

VI. CONCLUSION:

The different schemes of power-efficient class AB two-stage op-amps are introduced by using a current replication branch and adoptive loads have been experimentally tested. They achieve approximately symmetrical and high slew rate with very small additional static power dissipation and small additional circuitry.

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Author's:

P.Eswara Prasanna Kumar pursuing Masters degree in the institute SITS affiliated to JNTU Anantapur. He received B.Tech degree from Sri Venkateswara University, Tirupati. His interested areas of research include VLSI design

Mr.A.Madhukar babu was born in Kadapa, Andhra Pradesh, India. He received B.Tech degree in the year 2011 and M.Tech degree in the year 2013 from JNTU Anantapur. He is working as Assistant Professor in the Department of Electronics and Communications Engineering in SRTS, Kadapa. His interested areas of research.

Mr. G. Nagendra Prasad was born in Kadapa, Andhra Pradesh, India. He received B.Tech degree in the year 2002 and M.Tech degree in the year 2006 from Sri Venkateswara University Tirupati. Eight years of experience as a faculty in various institutes and colleges.He is working as Associate Professor in the Department of Electronics and Communications Engineering in SRTS, Kadapa. His interested areas of research include Wireless communications and Microwave engineerin